

MR2502, MR2504, MR2510

MR2504 and MR2510 are Preferred Devices

Medium-Current Silicon Rectifiers

... compact, highly efficient silicon rectifiers for medium-current applications requiring:

- High Current Surge — 400 Amperes @ $T_j = 175^\circ\text{C}$
- Peak Performance @ Elevated Temperature — 25 Amperes @ $T_c = 150^\circ\text{C}$
- Low Cost
- Compact, Molded Package — For Optimum Efficiency in a Small Case Configuration

Mechanical Characteristics:

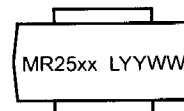
- Case: Epoxy, Molded
- Weight: 1.8 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminals are Readily Solderable
- Lead Temperature for Soldering Purposes: requires a custom temperature soldering profile
- Polarity: Cathode Polarity Band

**MEDIUM-CURRENT
SILICON RECTIFIERS
25 AMPERES
200-1000 VOLTS
DIFFUSED JUNCTION**



**MICRODE BUTTON
CASE 193**

MARKING DIAGRAM



MR25xx = Device Code
xx = 02, 04 or 10
L = Location Code
YY = Year
WW = Work Week



NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

MR2502, MR2504, MR2510

MAXIMUM RATINGS

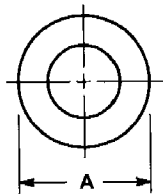
Characteristic	Symbol	MR2502	MR2504	MR2510	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	200	400	1000	Volts
Non-Repetitive Peak Reverse Voltage (Halfwave, single phase, 60 Hz peak)	V_{RSM}	240	480	1200	Volts
Average Rectified Forward Current (Single phase, resistive load, 60 Hz, $T_C = 150^\circ\text{C}$)	I_o	25			Amps
Non-Repetitive Peak Surge Current (Surge applied at rated load conditions, halfwave, single phase, 60 Hz)	I_{FSM}	400 (for 1 cycle)			Amps
Operating and Storage Junction Temperature Range	T_J, T_{stg}	- 65 to +175			$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case (Single Side Cooled)	$R_{\theta JC}$	1.0	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS

Characteristics and Conditions	Symbol	Max	Unit
Maximum Instantaneous Forward Voltage ($i_F = 78.5$ Amps, $T_C = 25^\circ\text{C}$)	v_F	1.18	Volts
Maximum Reverse Current (rated dc voltage) $T_C = 25^\circ\text{C}$ $T_C = 100^\circ\text{C}$	I_R	100 500	μA



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	8.43	8.69	0.332	0.342
B	4.19	4.45	0.165	0.175
D	5.54	5.64	0.218	0.222
F	5.94	6.25	0.234	0.246
M	5° NOM		5° NOM	

